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Introduction

The chairs would like to dedicate this volume to the memory of Professors Alois Krost, Bruno Meyer, and Fritz Henneberger. All three were frequent contributors to the Oxide-Based Materials and Devices conference and its predecessor, the Zinc Oxide Based Materials and Devices conference, at Photonics West. Krost, Meyer, and Henneberger will be sorely missed by the community, both personally and for their inestimable contributions to the field.

Ferechteh H. Teherani David C. Look David J. Rogers

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